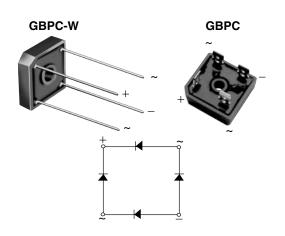


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COMPLIANT

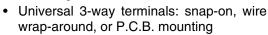
# Glass Passivated Single-Phase Bridge Rectifier

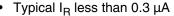


| PRIMARY CHARACTERISTICS |                            |  |  |  |  |  |  |
|-------------------------|----------------------------|--|--|--|--|--|--|
| I <sub>F(AV)</sub>      | 12 A, 15 A, 25 A, 35 A     |  |  |  |  |  |  |
| V <sub>RRM</sub>        | 50 V to 1000 V             |  |  |  |  |  |  |
| I <sub>FSM</sub>        | 200 A, 300 A, 300 A, 400 A |  |  |  |  |  |  |
| I <sub>R</sub>          | 5 μΑ                       |  |  |  |  |  |  |
| $V_{F}$                 | 1.1 V                      |  |  |  |  |  |  |
| T <sub>J</sub> max.     | 150 °C                     |  |  |  |  |  |  |

#### **FEATURES**







High surge current capability

Low thermal resistance

Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### TYPICAL APPLICATIONS

General purpose use in ac-to-dc bridge full wave rectification for power supply, home appliances, office equipment, industrial automation applications.

#### **MECHANICAL DATA**

Case: GBPC, GBPC-W

Epoxy meets UL 94V-0 flammability rating

**Terminals:** Nickel plated on faston lugs or silver plated on wire leads, solderable per J-STD-002 and JESD22-B102. E4 suffix for consumer grade. Suffix letter "W" added to indicate wire leads (e.g. GBPC12005W).

Polarity: As marked, positive lead by belevled corner

Mounting Torque: 20 inches-lbs. max.

| MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)                  |                                      |                                   |                          |     |     |     |     |                  |      |       |
|--|--------------------------------------|-----------------------------------|--------------------------|-----|-----|-----|-----|------------------|------|-------|
| PARAMETER  |                                      | SYMBOL                            | GBPC12, 15, 25, 35       |     |     |     |     |                  |      | LINUT |
|  |                                      |                                   | 005                      | 01  | 02  | 04  | 06  | 08               | 10   | UNIT  |
| Maximum repetitive peak reverse voltage  | <b>!</b>                             | $V_{RRM}$                         | 50                       | 100 | 200 | 400 | 600 | 800              | 1000 | ٧     |
| Maximum RMS voltage  |                                      | $V_{RMS}$                         | 35                       | 70  | 140 | 280 | 420 | 560              | 700  | ٧     |
| Maximum DC blocking voltage  |                                      | $V_{DC}$                          | 50                       | 100 | 200 | 400 | 600 | 800              | 1000 | ٧     |
| Maximum average forward rectified output current (Fig. 1)                        | GBPC12<br>GBPC15<br>GBPC25<br>GBPC35 | I <sub>F(AV)</sub>                | 12<br>15<br>25<br>35     |     |     |     |     | Α                |      |       |
| Peak forward surge current single sine-wave superimposed on rated load           | GBPC12<br>GBPC15<br>GBPC25<br>GBPC35 | I <sub>FSM</sub>                  | 200<br>300<br>300<br>400 |     |     |     |     | Α                |      |       |
| Rating (non-repetitive, for t greater than 1 ms and less than 8.3 ms) for fusing | GBPC12<br>GBPC15<br>GBPC25<br>GBPC35 | l <sup>2</sup> t                  | 160<br>375<br>375<br>660 |     |     |     |     | A <sup>2</sup> s |      |       |
| RMS isolation voltage from case to leads   |                                      | V <sub>ISO</sub>                  | 2500                     |     |     |     |     |                  |      | V     |
| Operating junction storage temperature range                                     |                                      | T <sub>J</sub> , T <sub>STG</sub> | - 55 to + 150            |     |     |     |     |                  | °C   |       |

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# GBPC12, GBPC15, GBPC25 & GBPC35

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted) |                                      |   |                |                    |    |    |    |    |    |    |      |
|---|--------------------------------------|---|----------------|--------------------|----|----|----|----|----|----|------|
| PARAMETER   |                                      | TEST  | SYMBOL         | GBPC12, 15, 25, 35 |    |    |    |    |    |    | UNIT |
|   |                                      | CONDITIONS  | STWIBUL        | 005                | 01 | 02 | 04 | 06 | 08 | 10 | UNII |
| Maximum instantaneous forward drop per diode                                      | GBPC12<br>GBPC15<br>GBPC25<br>GBPC35 | $I_F = 6.0 \text{ A}$ $I_F = 7.5 \text{ A}$ $I_F = 12.5 \text{ A}$ $I_F = 17.5 \text{ A}$ | V <sub>F</sub> | 1.1                |    |    |    |    | V  |    |      |
| Maximum reverse DC curr<br>DC blocking voltage per di                             |                                      | T <sub>A</sub> = 25 °C<br>T <sub>A</sub> = 125 °C   | I <sub>R</sub> | 5.0<br>500         |    |    |    | μΑ |    |    |      |
| Typical junction capacitano   | e per diode                          | 4 V, 1 MHz  | CJ             | 300                |    |    |    |    |    | pF |      |

| THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted) |                     |                |                    |    |    |            |    |    |    |      |
|---|---------------------|----------------|--------------------|----|----|------------|----|----|----|------|
| PARAMETER   |                     | SYMBOL         | GBPC12, 15, 25, 35 |    |    |            |    |    |    |      |
|   |                     |                | 005                | 01 | 02 | 04         | 06 | 08 | 10 | UNIT |
| Typical thermal resistance (1)  | GBPC12-25<br>GBPC35 | $R_{	heta JC}$ |                    |    |    | 1.9<br>1.4 |    |    |    | °C/W |

#### Notes:

- (1) With heatsink
- (2) Bolt down on heatsink with silicone thermal compound between bridge and mounting surface for maximum heat transfer with #10 screw

| ORDERING INFORMATION (Example) |                 |                        |               |               |  |  |  |  |  |
|--------------------------------|-----------------|------------------------|---------------|---------------|--|--|--|--|--|
| PREFERRED P/N                  | UNIT WEIGHT (g) | PREFERRED PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |  |  |  |
| GBPC1206-E4/51                 | 15.79           | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC1506-E4/51                 | 15.79           | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC2506-E4/51                 | 15.79           | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC3506-E4/51                 | 15.79           | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC1206W-E4/51                | 13.8            | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC1506W-E4/51                | 13.8            | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC2506W-E4/51                | 13.8            | 51                     | 100           | Paper box     |  |  |  |  |  |
| GBPC3506W-E4/51                | 13.8            | 51                     | 100           | Paper box     |  |  |  |  |  |

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#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

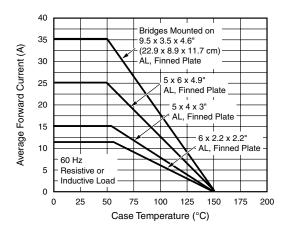


Figure 1. Maximum Output Rectified Current

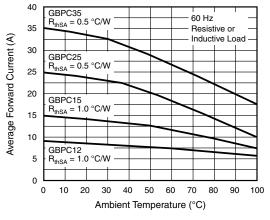


Figure 2. Maximum Output Rectified Current

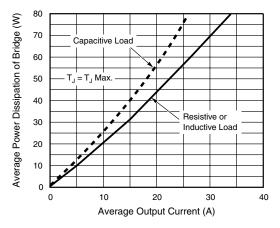


Figure 3. Maximum Power Dissipation

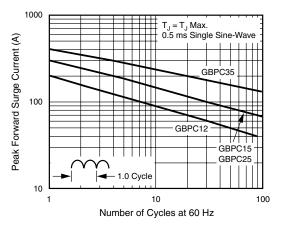


Figure 4. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

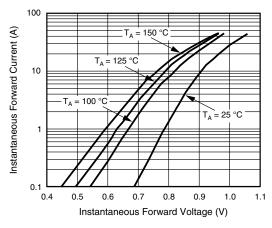


Figure 5. Typical Instantaneous Forward Characteristics Per Diode

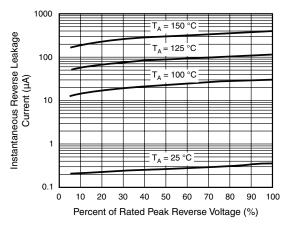


Figure 6. Typical Reverse Leakage Characteristics Per Diode

# GBPC12, GBPC15, GBPC25 & GBPC35

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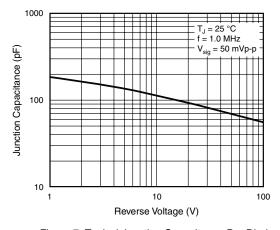


Figure 7. Typical Junction Capacitance Per Diode

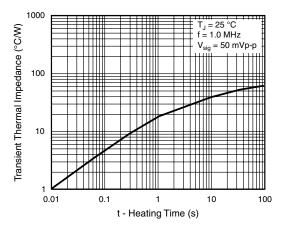
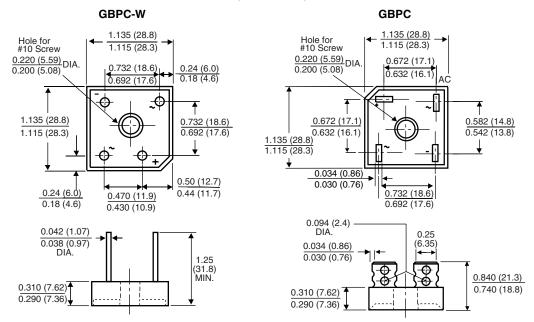


Figure 8. Typical Transient Thermal Impedance Per Diode

## PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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